

2SC3611

Silicon NPN epitaxial planar type

For video amplifier

■ Features

- High transition frequency f_T
- Small collector output capacitance C_{ob}
- Wide current range
- TO-126B package which requires no insulation plate for installation to the heat sink

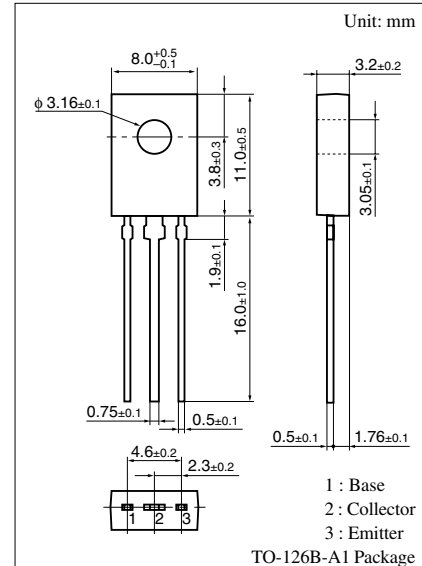
■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

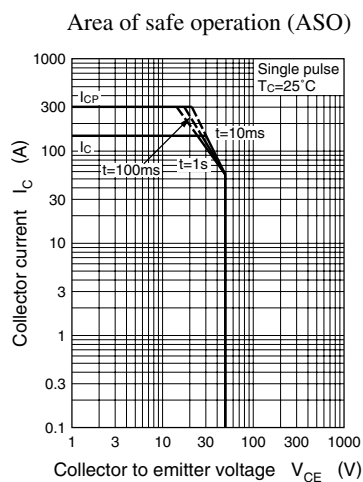
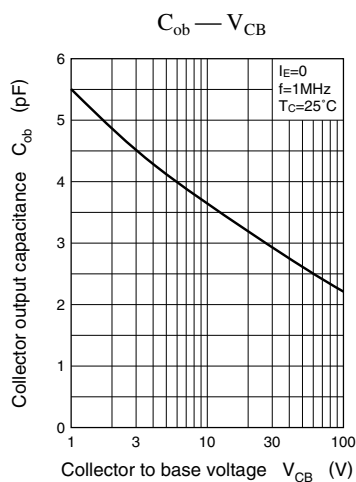
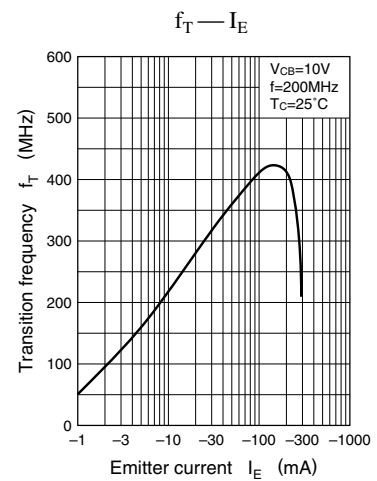
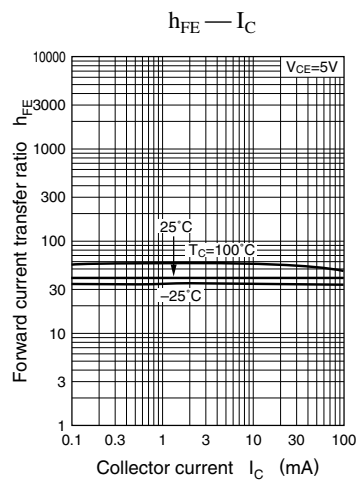
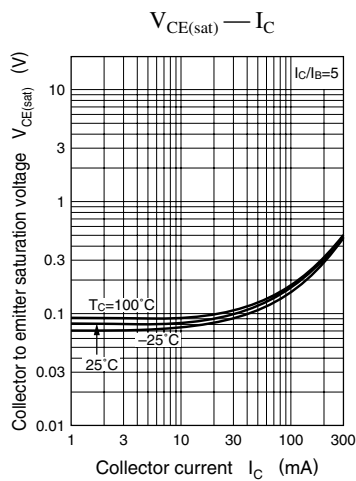
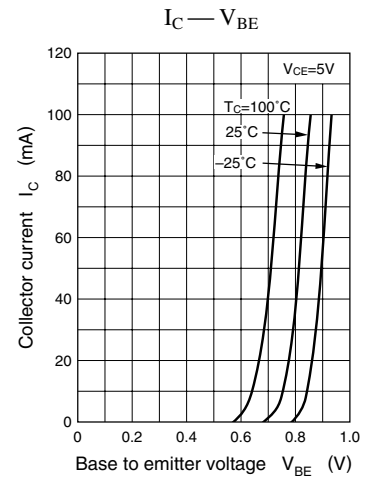
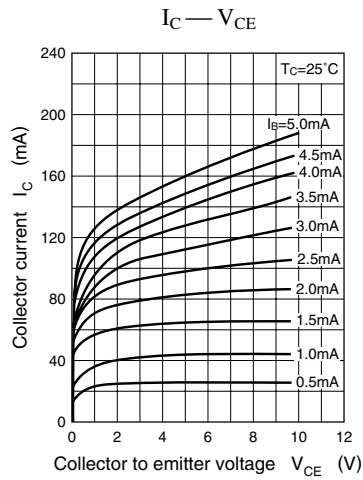
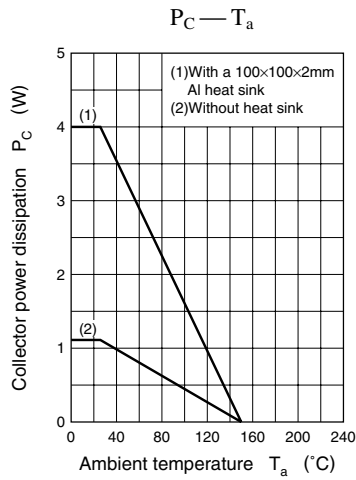
| Parameter | | Symbol | Rating | Unit |
|------------------------------|-----------------------|------------------|-------------|------|
| Collector to base voltage | | V _{CBO} | 110 | V |
| Collector to emitter voltage | | V _{CER} | 100 | V |
| | | V _{CEO} | 50 | V |
| Emitter to base voltage | | V _{EBO} | 3.5 | V |
| Peak collector current | | I _{CP} | 300 | mA |
| Collector current | | I _C | 150 | mA |
| Collector power dissipation | T _C = 25°C | P _C | 1.2 | W |
| | T _a = 25°C | | 4.0 * | |
| Junction temperature | | T _j | 150 | °C |
| Storage temperature | | T _{stg} | -55 to +150 | °C |

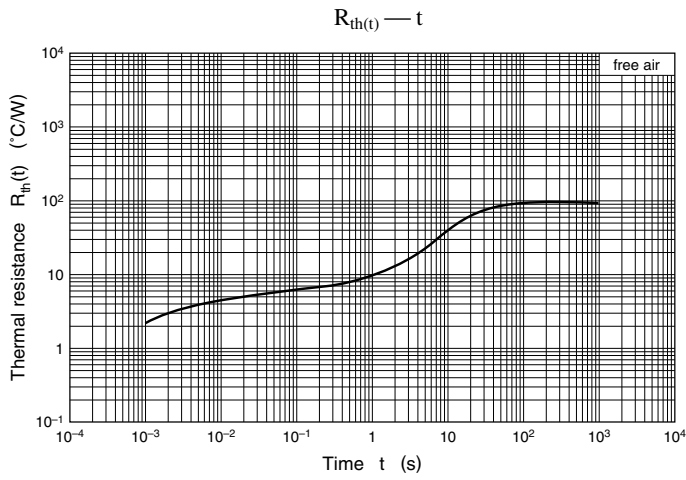
Note) *: With a $100 \times 100 \times 2$ mm Al heat sink

■ Electrical Characteristics $T_C = 25^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|---------------|---|-----|-----|-----|---------------|
| Collector cutoff current | I_{CEO} | $V_{CE} = 35 \text{ V}, I_B = 0$ | | | 10 | μA |
| Collector to base voltage | V_{CBO} | $I_C = 100 \mu\text{A}, I_E = 0$ | 110 | | | V |
| Collector to emitter voltage | V_{CER} | $I_C = 500 \mu\text{A}, R_{BE} = 470 \Omega$ | 100 | | | V |
| | V_{CEO} | $I_C = 1 \text{ mA}, I_B = 0$ | 50 | | | V |
| Emitter to base voltage | V_{EBO} | $I_E = 100 \mu\text{A}, I_C = 0$ | 3.5 | | | V |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 5 \text{ V}, I_C = 100 \text{ mA}$ | 20 | | | |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | | 0.5 | V |
| Transition frequency | f_{T1} | $V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$ | | 300 | | MHz |
| | f_{T2} | $V_{CB} = 10 \text{ V}, I_E = -110 \text{ mA}, f = 200 \text{ MHz}$ | | 350 | | MHz |
| Collector output capacitance | C_{ob} | $V_{CB} = 30 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | | 3 | | pF |







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